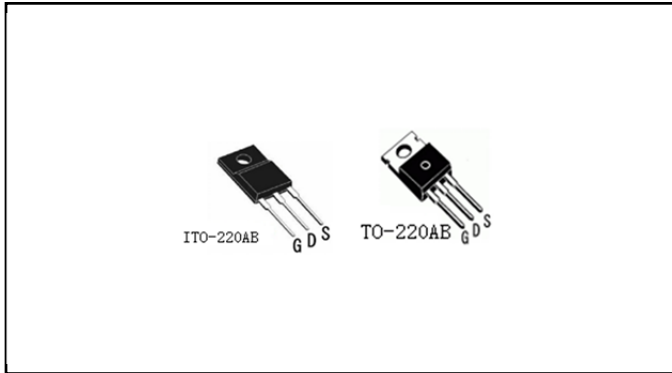
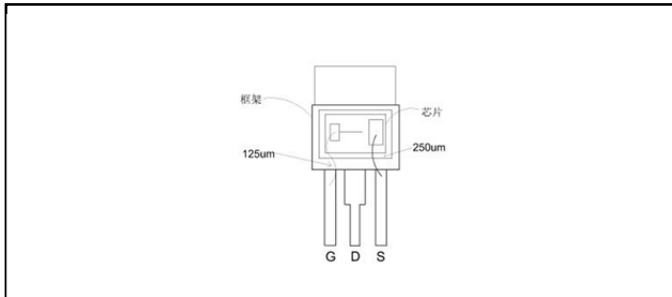


N-Channel Enhancement Mode Mosfet



Feature:

- Low Crss
- Low Gate Charge
- Fast Switching
- Improved ESD Capability
- Improved dv/dt Capability
- 100% Avalanche Energy Test



Mechanical Data:

- **Package: MOS**
Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- **Terminal: Tin plated leads.**
Solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked on body

■ Ordering Information

P/N	PACKAGE	PACKING CODE	UNIT WEIGHT(g)	MINIIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
YJ7N60CI	ITO-220AB	B1	Approximate 1.7	50	1000	5000	TUBE
YJ7N60CZ	TO-220AB	B1	Approximate 2.0	50	1000	5000	TUBE
YJ7N60CM	TO-263	B1	Approximate 1.4	50	1000	5000	TUBE

■ Maximum Ratings (T_a=25°C Unless otherwise specified)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V _{DSS}	600	V
Continues Drain Current	I _D	T _c =25°C	7*
		T _c =100°C	4.0*
Plused Drain Current (note 1)	I _{DM}	25	A
Gate-to-Source Voltage	V _{GS}	±30	V
Single Pulsed Avalanche Energy (note 2)	E _{AS}	400	mJ
Avalanche Current (note 1)	I _{AR}	7.0	A
Repetitive Avalanche Energy (note 1)	E _{AR}	14.5	mJ
Peak Diode Recovery (note 3)	dv/dt	4.5	V/ns
Power Dissipation	P _D T _c =25°C	TO-220AB	147
		ITO-220AB	48
Power Dissipation Derating Factor	P _{D(DF)} Above 25°C	TO-220AB	1.18
		ITO-220AB	0.38
Operating and Storage Temperature Range	T _J , T _{STG}	150, -55~+150	°C
Maximum Temperature for Soldering	T _L	300	°C

■ Electrical Characteristics (T_a=25°C Unless otherwise specified)

Off-Characteristics						
Parameter	Symbol	Tests Conditions	Min	Type	Max	Unit
Drain-Source Breakdown Voltage	BV _{DSS}	I _D =250μA, V _{GS} =0V	600	-	-	V
Breakdown Voltage Temperature Coefficient	ΔBV _{DSS} /ΔT _J	I _D =250μA, referenced to 25°C	-	0.7	-	V/°C
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =600V, V _{GS} =0V, T _c =25°C	-	-	1	μA
		V _{DS} =480V, T _c =125°C	-	-	10	
Gate-body leakage current, forward	I _{GSSF}	V _{DS} =0V, V _{GS} =30V	-	-	100	nA
Gate-body leakage current, reverse	I _{GSSR}	V _{DS} =0V, V _{GS} = -30V	-	-	-100	nA



On-Characteristics						
Parameter	Symbol	Tests Conditions	Min	Type	Max	Unit
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D=250\mu A$	2.0	-	4.0	V
Static Drain-Source On-Resistance	$R_{DS(ON)}$	$V_{GS}=10V, I_D=3.5A$	-	1.1	1.3	Ω
Forward Transconductance	g_{fs}	$V_{DS} = 40V, I_D=3.5A$ (note4)	-	6.5	-	S

Dynamic Characteristics						
Parameter	Symbol	Tests Conditions	Min	Type	Max	Unit
Input capacitance	C_{iss}	$V_{DS}=25V, V_{GS}=0V, f=1.0MHz$	-	980	1760	pF
Output capacitance	C_{oss}		-	95	178	pF
Reverse transfer capacitance	C_{rss}		-	13	20	pF

Switching Characteristics						
Parameter	Symbol	Tests Conditions	Min	Type	Max	Unit
Turn-On delay time	$t_d(on)$	$V_{DD}=300V, I_D=7A, R_G=25\Omega$ (note 4, 5)	-	35	75	ns
Turn-On rise time	t_r		-	80	170	ns
Turn-Off delay time	$t_d(off)$		-	130	265	ns
Turn-Off Fall time	t_f		-	85	180	ns
Total Gate Charge	Q_g	$V_{DS}=480V, I_D=7A, V_{GS}=10V$ (note 4, 5)	-	45	60	nC
Gate-Source charge	Q_{gs}		-	6.8	-	nC
Gate-Drain charge	Q_{gd}		-	18	-	nC

Drain-Source Diode Characteristics and Maximum Ratings						
Parameter	Symbol	Tests Conditions	Min	Type	Max	Unit
Maximum Continuous Drain-Source Diode Forward Current		I_S	-	-	7	A
Maximum Pulsed Drain-Source Diode Forward Current		I_{SM}	-	-	25	A
Drain-Source Diode Forward Voltage	V_{SD}	$V_{GS}=0V, I_S=7A$	-	-	1.4	V
Reverse recovery time	t_{rr}	$V_{GS}=0V, I_S=7A$ $di_F/dt=100A/\mu s$ (note 4)	-	415	-	ns
Reverse recovery charge	Q_{rr}		-	4.3	-	μC

■ Thermal Characteristics (T_a=25°C Unless otherwise specified)

Parameter	Symbol		Max	Unit
Thermal Resistance, Junction to Case	Rth(j-c)	TO-220AB	0.85	°C/W
		ITO-220AB	2.6	
Thermal Resistance, Junction to Ambient	Rth(j-A)	TO-220AB	62.5	°C/W
		ITO-220AB	62.5	

* Drain current limited by maximum junction temperature

Notes:

- 1: Pulse width limited by maximum junction temperature
- 2: L=11.5mH, I_{AS}=7A, V_{DD}=50V, R_G=25Ω, Starting T_J=25°C
- 3: I_{SD} ≤ 7A, di/dt ≤ 300A/μs, V_{DD} ≤ BV_{DSS}, Starting T_J=25°C
- 4: Pulse Test: Pulse Width ≤ 300μs, Duty Cycles ≤ 2%
- 5: Essentially independent of operating temperature

■ Characteristics (Typical)

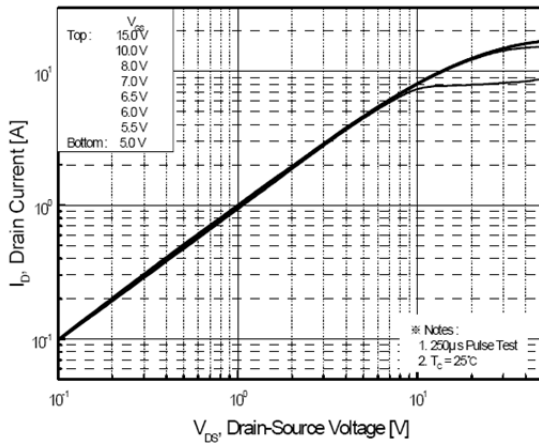


Fig. 1 On-State Characteristics

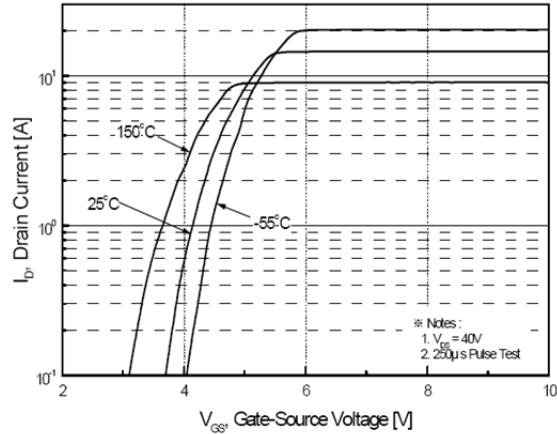


Fig. 2 Transfer Characteristics

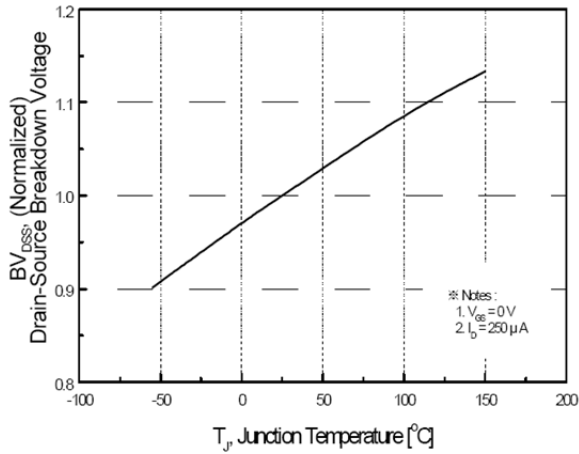


Fig. 3 Breakdown Voltage Variation vs Temperature

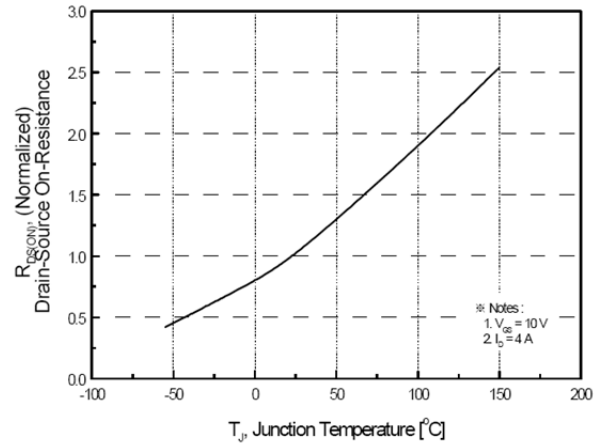


Fig. 4 On-Resistance Variation vs Temperature

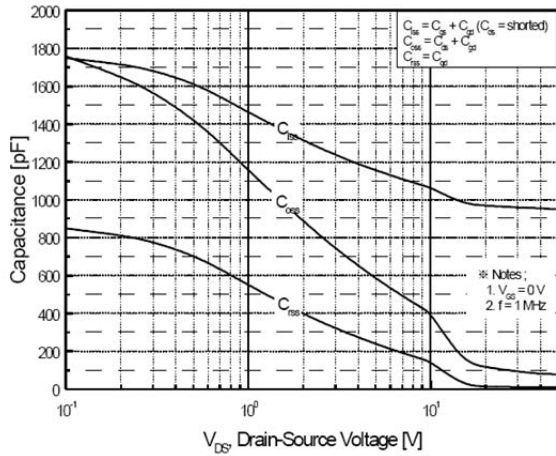


Fig. 5 Capacitance Characteristics

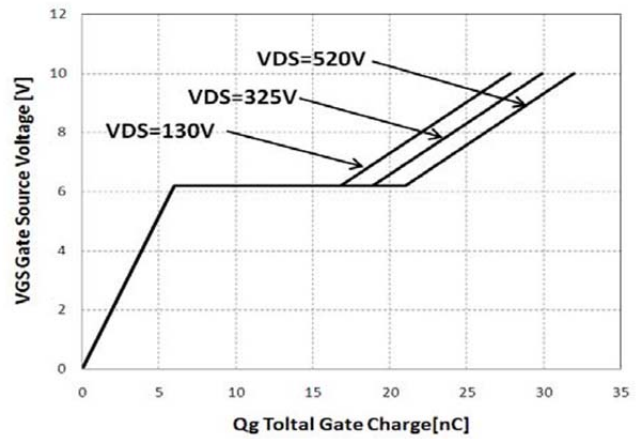


Fig. 6 Gate Charge Characteristics

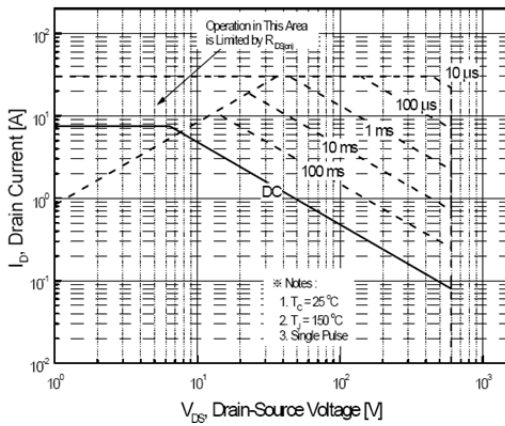


Fig. 7 Maximum Safe Operating Area

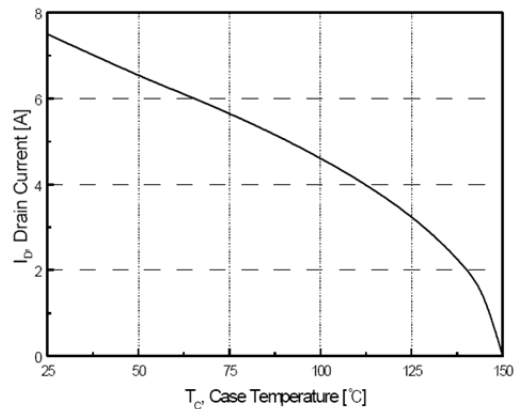


Fig. 8 Maximum Drain Current vs Case Temperature

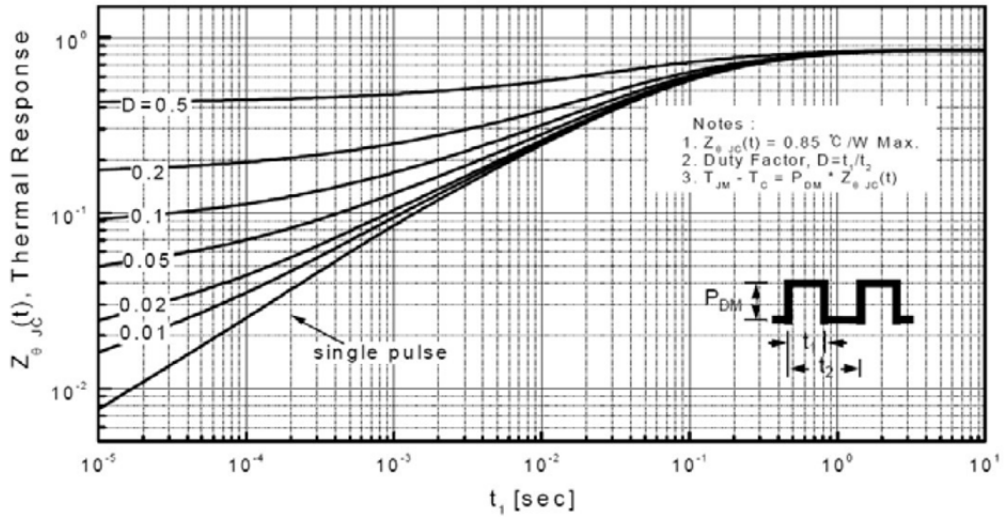


Fig. 9 Transient Thermal Response Curve(TO-220AB)

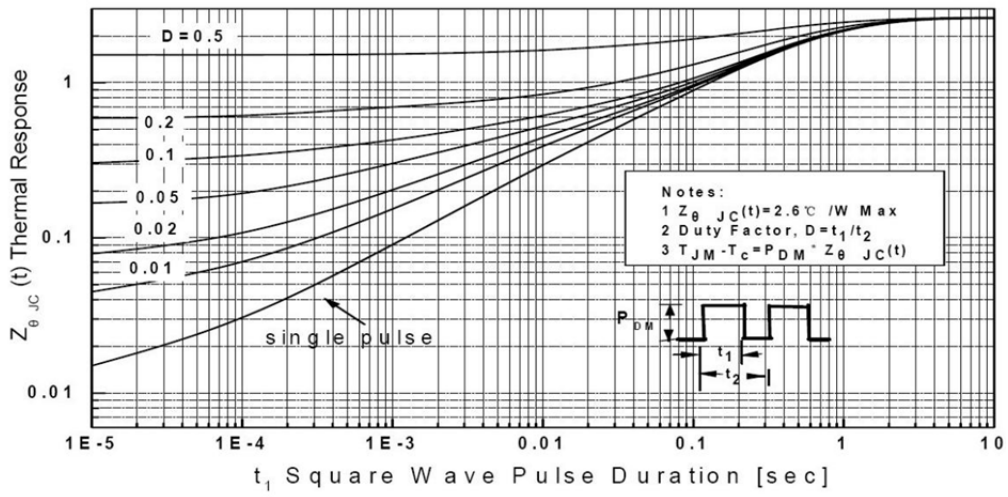
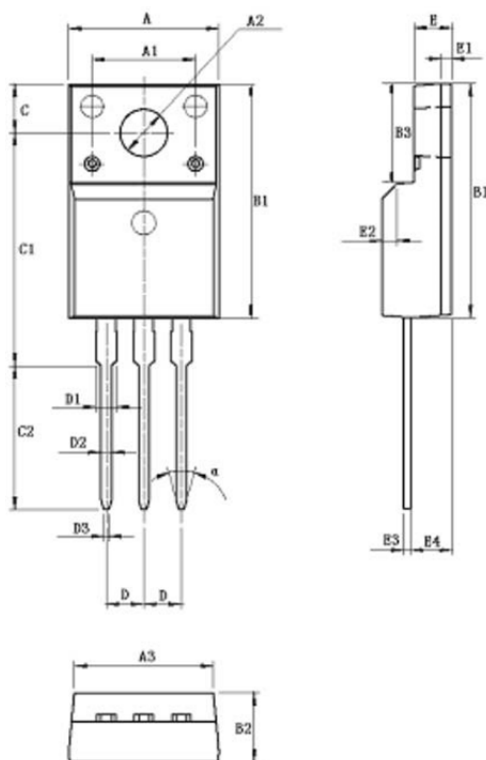


Fig. 10 Transient Thermal Response Curve(ITO-220AB)

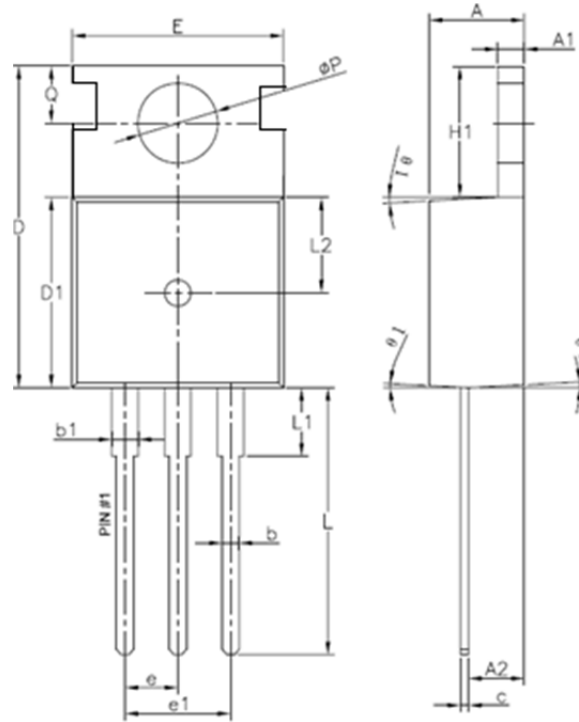
■ Outline Dimensions

ITO-220AB



Symbol	Min	Max	Symbol	Min	Max
A	9.96	10.36	D	2.54	
A1	7.00		D1	1.15	1.35
A2	3.08	3.28	D2	0.70	0.90
A3	9.25	9.65	D3	0.28	0.48
B1	15.70	16.10	E	2.34	2.74
B2	4.50	4.90	E1	0.70	
B3	6.20	6.80	E2	1.0×45°	
C	3.20	3.40	E3	0.36	0.65
C1	15.20	16.00	E4	2.55	2.95
C2	9.75	10.15	a(度)	30°	

TO-220AB



Symbol	Min	Normal	Max	Symbol	Min	Normal	Max
A	4.4	4.5	4.6	e		2.54	
A1	1.27	1.3	1.33	e1		5.08	
A2	2.3	2.4	2.5	H1	6.3	6.5	6.7
b	0.7	/	0.9	L	13.0	13.38	13.5
b1	1.25		1.42	L1	/	/	3.5
c	0.45	0.5	0.6	L2		4.6	
D	15.3	15.7	16.1	ϕP	3.55	3.6	3.65
D1	9.1	9.2	9.3	Q	2.73	/	2.87
E	9.7	9.9	10.2	θ_1 (°)	1	3	5



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